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9/20/02

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re U.S. Patent Application )  
Applicant: Hongyong Zhang )  
Serial No. 09/468,489 )  
Filed: December 20, 1999 )  
For: THIN FILM TRANSISTOR )  
HAVING LIGHTLY AND )  
HEAVILY DOPED SOURCE/ )  
DRAIN REGIONS AND ITS )  
MANUFACTURE )  
Art Unit: 2814 )  
Examiner: Quach, T. )

I hereby certify that this paper is being deposited with  
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Patents, Washington, D.C. 20231, on this date.

August 28, 2002  
Date

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AMENDMENT D

Assistant Commissioner for Patents  
Washington, D.C. 20231

Dear Sir:

In response to the Office Action mailed March 28, 2002, please amend the  
above-identified Application as follows:

IN THE SPECIFICATION:

Please replace the paragraph beginning on page 3, line 19, with the following  
amended paragraph: